Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-361-9894

| Inclosure Material: | |
|--------------------------|--|
| Ceramic and metal | |
| Overall Length: | |
| 0.970 inches | |
| Overall Diameter: | |
| 1.930 inches | |
| Mounting Method: | |
| Press fit | |
| Semiconductor Materia | al: |
| Silicon | |
| Voltage Rating In Volts | Per Characteristic: |
| 2600.0 repetitive peak r | everse voltage and 2600.0 repetitive peak off-state voltage |
| Current Rating Per Cha | aracteristic: |
| 600.00 amperes forward | current, total rms horsepower metric and 380.00 amperes forward current, total rms universal |
| Terminal Type And Qu | antity: |
| 2 case and 2 insulated w | vire lead |
| Shelf Life: | |
| N/a | |
| Unit Of Measure: | |
| | |
| Demilitarization: | |
| No | |
| Fiig: | |
| A110a0 | |